Vishay General Semiconductor

RoHS

Dual Common Cathode High Voltage Schottky Rectifier

Low Leakage Current 5.0 µA





PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 10 A				
V _{RRM}	200 V				
I _{FSM}	290 A				
V_{F}	0.75 V				
T _J max.	175 °C				
Package	TO-220AB, ITO-220AB, TO-262AA				
Diode variations	Common cathode				

FEATURES

- Power pack
- · Guardring for overvoltage protection
- · Low power loss, high efficiency
- Low forward voltage drop
- High frequency operation
- Solder dip 275 °C max., 10 s per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency inverters, freewheeling, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, and TO-262AA

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PARAMETER	SYMBOL	VALUE	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	200	V	
Working peak reverse voltage		V_{RWM}	200	V
Maximum DC blocking voltage		V_{DC}	200	V
Maximum average forward rectified current	total device	I _{F(AV)}	20	А
	per diode		10	
Peak forward surge current 8.3 ms single half sine-wave on rated load per diode	forward surge current 8.3 ms single half sine-wave superimposed ed load per diode		290	А
Peak repetitive reverse current per diode at t_p = 2 μ s, 1 k	I _{RRM}	1.0	Α	
Peak non-repetitive reverse surge energy per diode (8/20	E _{RSM}	20	mJ	
Non-repetitive avalanche energy per diode at 25 °C, I _{AS} =	E _{AS}	20	mJ	
Electrostatic discharge capacitor voltage human body model air discharge: C = 100 pF, R = 1.5 k Ω		V _C	25	kV
Voltage rate of change (rated V _R)	dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-65 to +175	°C
Isolation voltage (ITO-220AB only) from terminals to heatsink t = 1 min		V _{AC}	1500	V

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Maximum instantaneous forward voltage per diode	I _F = 10 A	T _C = 25 °C		0.81	0.88		
	I _F = 10 A	T _C = 125 °C	V _E (1)	0.65	0.75	V	
	I _F = 20 A	T _C = 25 °C	v F (/	0.87	0.97	7 v	
	I _F = 20 A	T _C = 125 °C		0.74	0.85	1	
Maximum reverse current per diode		T _J = 25 °C	I _R ⁽¹⁾	5.0		μA	
at working peak reverse voltage		T _J = 125 °C	IR (''	1.0		mA	
Typical junction capacitance	4.0 V, 1 MHz		CJ	250		pF	

Notes

 $^{^{(1)}}$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	SB	UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	2.0	4.0	2.0	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR20H200CT-E3/45	2.06	45	50/tube	Tube		
ITO-220AB	MBRF20H200CT-E3/45	2.20	45	50/tube	Tube		
TO-262AA	SB20H200CT-1E3/45	1.58	45	50/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES (T_C = 25 °C unless otherwise noted)

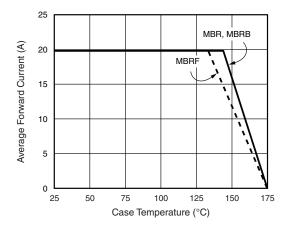


Fig. 1 - Forward Derating Curve (Total)

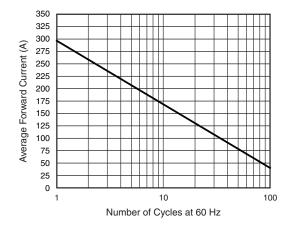
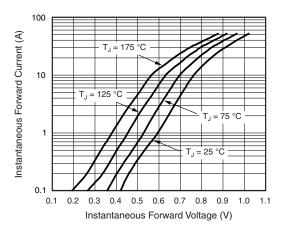


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

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Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

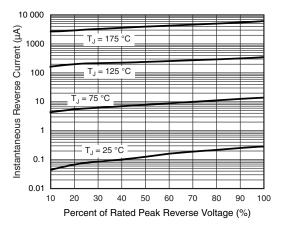


Fig. 4 - Typical Reverse Characteristics Per Diode

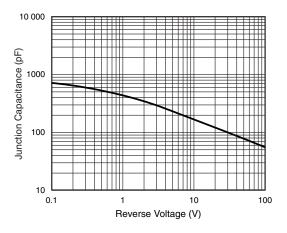


Fig. 5 - Typical Junction Capacitance Per Diode

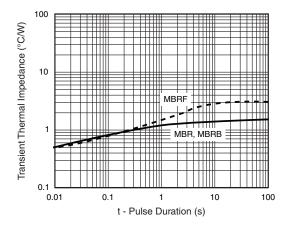


Fig. 6 - Typical Transient Thermal Impedance Per Diode

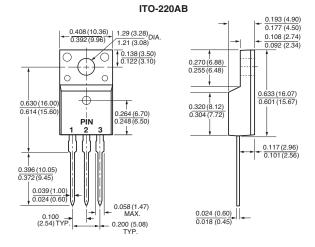


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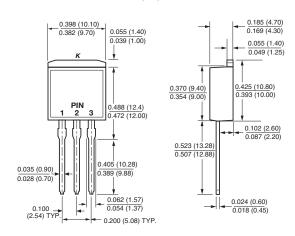
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB 0.398 (10.10) 0.382 (9.70) 0.185 (4.70) 0.150 (3.80) 0.343 (8.70) TYP. DIA. + 0.114 (2.90) 0.106 (2.70) 0.154 (3.90) 0.067 (1.70) TYP. 0.638 (16.20) 0.598 (15.20) 0.331(8.40) TYP PIN 1.161 (29.48) 1.106 (28.08) 0.118 (3.00) TYP. 0.102 (2.60) 0.087 (2.20) 0.523 (13.28) 0.507 (12.88) 0.064 (1.62) 0.100 (2.54) -0.200 (5.08) TYP.



TO-262AA





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